

Vishay Semiconductors

Band Switching Diodes



FEATURES

- Silicon planar diodes
- Low dynamic forward resistance
- Low diode capacitance
- High reverse impedance
- AEC-Q101 qualified

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



ROHS

MECHANICAL DATA

Case: MiniMELF SOD-80
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

APPLICATIONS

• Band switching in VHF-tuners

PARTS TABLE					
PART	TYPE DIFFERENTIATION	ORDERING CODE	REMARKS		
BA682	$V_R = 35 \text{ V}, r_f \text{ at } I_F \text{ 3 mA} = \text{max. } 0.7 \Omega$	BA682-GS18 or BA682-GS08	Tape and reel		
BA683	$V_R = 35 \text{ V}, r_f \text{ at } I_F 3 \text{ mA} = \text{max. } 1.2 \Omega$	BA683-GS18 or BA683-GS08	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	35	V	
Forward continuous current		I _F	100	mA	

Note

 $^{(1)}$ $T_{amb} = 25$ °C, unless otherwise specified

THERMAL CHARACTERISTICS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W
Junction temperature		Tj	150	°C
Storage temperature range		T _{sta}	- 55 to + 150	°C

Note

 $^{(1)}$ $T_{amb} = 25$ °C, unless otherwise specified

ELECTRICAL CHARACTERISTICS (1)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA		V_{F}			1000	mV
Reverse current	V _R = 20 V		I _R			50	nA
	f = 100 MHz, V _R = 1 V		C _{D1}			1.5	pF
Diode capacitance	f = 100 MHz, V _R = 3 V	BA682	C _{D2}			1.25	pF
		BA683	C _{D2}			1.2	pF
Dynamic forward resistance	f = 200 MHz, I _F = 3 mA	BA682	r _{f1}			0.7	Ω
		BA683	r _{f1}			1.2	Ω
	f = 200 MHz, I _F = 10 mA	BA682	r _{f2}			0.5	Ω
		BA683	r _{f2}			0.9	Ω

Note

(1) T_{amb} = 25 °C, unless otherwise specified

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TYPICAL CHARACTERISTICS Tamb = 25 °C, unless otherwise specified

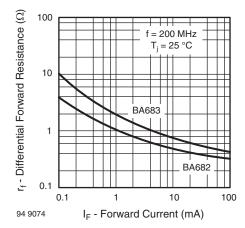


Fig. 1 - Dynamic Forward Resistance vs. Forward Current

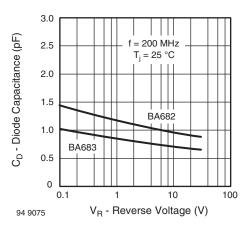
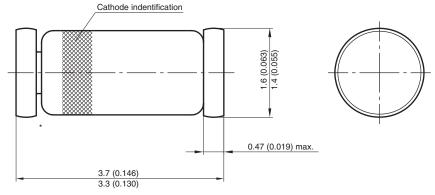
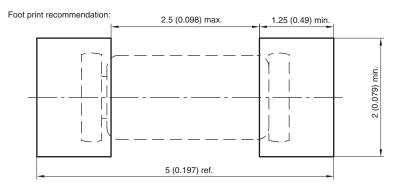


Fig. 1 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): MiniMELF SOD-80



* The gap between plug and glass can be either on cathode or anode side



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070



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Revision: 02-Oct-12 Document Number: 91000